

一、静电场

例. 带电体在外场中.

(1) 边长为a的正六边形.

(2) 稳定静电场.

(3) 将两个上电荷移至无穷远, 外力所做的功.

例. 元电荷, 相距a.

计算一个离子与其他的相互作用能.

例. 均匀带电圆环面上的静电力.

例. 均匀带电球体内面上的静电力.

例. 聚极上荷为球体外力做功.

例. 边长为a的正六边形.

(1) 稳定静电场.

(2) 将两个上电荷移至无穷远, 外力所做的功.

对环上任意一点的电势:

$$\Psi = \frac{2Q}{4\pi\epsilon_0 a} - \frac{Q}{4\pi\epsilon_0 \sqrt{3}a} + \frac{Q}{4\pi\epsilon_0 2a}$$

$$= \frac{Q}{4\pi\epsilon_0 a} \left(2 - \frac{1}{\sqrt{3}} + \frac{1}{2} \right) = \frac{Q}{4\pi\epsilon_0 a} \times \left(\frac{5}{2} - \frac{1}{\sqrt{3}} \right)$$

$$\Psi_1 = -\Psi_2$$

$$W = \frac{1}{2} (3Q\Psi_1 + 3(-Q)\Psi_2) \\ = \frac{3}{2} (Q \times \left(-\frac{Q(\sqrt{3}-2)}{4\pi\epsilon_0 a} + (-Q) \right) \left(\frac{Q(\sqrt{3}-2)}{4\pi\epsilon_0 a} \right)) \\ = -\frac{3}{2} \times 2 \frac{Q^2 (\sqrt{3}-2)}{4\pi\epsilon_0 a} = \frac{3Q^2}{4\pi\epsilon_0 a} \left(\frac{2}{\sqrt{3}} - \frac{5}{2} \right) < 0.$$

移动电荷

$$\rightarrow \Psi_{11} = \frac{Q}{4\pi\epsilon_0 a} - \frac{Q}{4\pi\epsilon_0 \sqrt{3}a} - \frac{Q}{4\pi\epsilon_0 2a} = \frac{Q}{4\pi\epsilon_0 a} \left(\frac{1}{\sqrt{3}} - \frac{3}{2} \right)$$

$$\Psi_{22} = \frac{1}{2} (Q \times \Psi_{11} - Q \Psi_{22} + Q \Psi_{22} - Q \Psi_{11}) \\ = \frac{1}{2} \left(\frac{Q^2}{4\pi\epsilon_0 a} \left(\frac{1}{\sqrt{3}} - \frac{3}{2} \right) - \frac{Q^2}{4\pi\epsilon_0 a} \left(2 - \frac{1}{\sqrt{3}} \right) \right)$$

$$+ \frac{Q^2}{4\pi\epsilon_0 a} \left(\frac{1}{\sqrt{3}} - 2 \right) - \frac{Q^2}{4\pi\epsilon_0 a} \left(\frac{1}{2} - \frac{1}{\sqrt{3}} \right)$$

$$= \frac{Q^2}{4\pi\epsilon_0 a} \left(\frac{1}{\sqrt{3}} - \frac{3}{2} + \frac{1}{\sqrt{3}} - 2 \right) = \frac{Q^2}{4\pi\epsilon_0 a} \left(\frac{2}{\sqrt{3}} - \frac{7}{2} \right)$$

$$W_1 = \frac{Q^2}{4\pi\epsilon_0 a}, \quad \therefore W = \frac{Q^2}{4\pi\epsilon_0 a} \left(\frac{2}{\sqrt{3}} - \frac{9}{2} \right) > 0.$$

$$\text{外力做功} = W' - W = \frac{Q^2}{4\pi\epsilon_0 a} \left(1 - \frac{9}{2} \right) > 0.$$

例. 元电荷, 相距a.

计算一个离子与其他的相互作用能.

$$\Psi = -\frac{Q}{4\pi\epsilon_0 a} + 2 \frac{Q}{4\pi\epsilon_0 2a} - \dots = \frac{Q}{2\pi\epsilon_0 a} \left(-1 + \frac{1}{2} - \frac{1}{3} + \dots \right)$$

$$= \frac{Q}{2\pi\epsilon_0 a} \sum_{n=1}^{\infty} (-1)^n \frac{1}{n} = \frac{Q}{2\pi\epsilon_0 a} \ln 2.$$

例. 均匀带电圆环面上的静电力.

$$\text{球面电势 } \Psi = \frac{Q}{4\pi\epsilon_0 a}$$

$$\text{静电能 } W = \frac{1}{2} \int d\varphi \Psi = \frac{1}{2} Q \frac{Q}{4\pi\epsilon_0 a} = \frac{Q^2}{8\pi\epsilon_0 a}.$$

例. 均匀带电球体内面上的静电力.

$$\vec{E} = \begin{cases} \frac{1}{4\pi\epsilon_0 r^2} \frac{Q}{r^2} \hat{Q}, & r < R \\ \frac{Q}{4\pi\epsilon_0 R^2}, & r \geq R \end{cases}$$

$$U = \begin{cases} \frac{Q}{4\pi\epsilon_0 R} + \frac{Qr^2}{24\pi\epsilon_0 R^3}, & r < R \\ \frac{Qr^2}{4\pi\epsilon_0 R^2}, & r \geq R \end{cases}$$

$$\text{球内静电能 } W = \frac{1}{2} \int_{R_0}^R \frac{Qr^2}{4\pi\epsilon_0 R^3} \left(1 - \frac{1}{R^2} \right) \times \rho 4\pi r^2 dr \\ = \frac{4\pi\epsilon_0 \rho^2}{15} R^5 = \frac{3}{5} \frac{Q^2}{4\pi\epsilon_0 a}.$$

例. 聚极上荷为球体外力做功.

$$\text{假设已聚成半径r的球, } r < a.$$

$$\text{球内电势 } \Psi_r = \frac{Qr}{4\pi\epsilon_0 r}$$

则电荷为半径r到dr的电荷时: $dQ = \rho dV$.

$$\text{外力做功 } P_{sd} dr = \frac{Q}{4\pi\epsilon_0 r} \cdot \frac{r^3}{R^3} Q \times \frac{4\pi r^2 dr}{4\pi\epsilon_0 a^3} Q \\ = \frac{3Q^2}{4\pi\epsilon_0 a^3} r^4 dr.$$

$$\therefore \text{总电荷做功 } W = \int_0^a \frac{3Q^2}{4\pi\epsilon_0 a^3} r^4 dr \\ = \frac{3Q^2}{4\pi\epsilon_0 a^6} \frac{1}{5} r^5 = \frac{-3Q^2}{20\pi\epsilon_0 a^6}.$$

(2) 带电体系

例. 带电极子的势能.

外向中的电势能:

带电极子相互作用能:

例. 环形电容器的静电能.

例. 球形电容器.

例. 平行板电容器.

(3) 能量密度.

例. 环形电容器的静电能.

例. 把电荷为q的粒子从无限远处移到半径为R, 厚度为d的空心导体球壳中心, 此过程电场力做多少功?

例. 平行板电容器板间充满ε的介质, 间距S之间距d, 则在极板上带+Q和-Q的电荷, 外界需要抵抗静电力做多少功?

2. 例. 环形电容器的静电能.

$$\vec{E}_{\text{内}} = \frac{Q_1}{4\pi\epsilon_0 r^2} \hat{r}, \quad \vec{E}_{\text{外}} = \frac{(Q_1 + Q_2)}{4\pi\epsilon_0 R^2} \hat{r}.$$

带电荷总量 $W_{\text{电}} = \frac{Q_1^2}{32\pi^2 \epsilon_0} \times \frac{1}{r^2}$

$W_{\text{电}} = \frac{(Q_1 + Q_2)^2}{32\pi^2 \epsilon_0} \times \frac{1}{R^2}$.

$$W_{\text{电}} = \iiint w_{\text{电}} dV = \frac{Q_1^2}{32\pi^2 \epsilon_0} \int_{\frac{R}{2}}^R \frac{1}{r^2} 4\pi r^2 dr = \frac{1}{2} \frac{Q_1^2}{4\pi\epsilon_0} \left(\frac{1}{R} - \frac{1}{2} \right) = \frac{Q_1^2}{2\epsilon_0 R}.$$

$W_{\text{电}} = \iiint w_{\text{电}} dV = (Q_1 + Q_2)^2 \int_{\frac{R}{2}}^R \frac{1}{r^2} 4\pi r^2 dr = \frac{1}{2} \frac{(Q_1 + Q_2)^2}{4\pi\epsilon_0} \frac{1}{d}.$

例. 把电荷为q的粒子从无限远处移到半径为R, 厚度为d的空心导体球壳中心, 此过程电场力做多少功?

$$\vec{E} = \frac{q}{4\pi\epsilon_0 r^2} \hat{r}$$

$V = \frac{q}{4\pi\epsilon_0 R}$

原: 无限远激发电场为 $E = \frac{q}{4\pi\epsilon_0 r^2}$.
在空壳间后: 移至导体中心, 导体内外 $E = 0$.

$$W = \frac{1}{2} \iiint \epsilon_0 E^2 dV + \frac{1}{2} \iiint \epsilon_0 E^2 dV$$

$\Delta W = W_1 - W_2 = -\frac{1}{2} \int_{2R}^{R_0} \frac{q^2}{4\pi\epsilon_0 r^2} \cdot 4\pi r^2 dr$

$= -\frac{q^2}{8\pi\epsilon_0} \int_{2R}^{R_0} \frac{1}{r^2} dr = \frac{q^2}{8\pi\epsilon_0} \left(\frac{1}{R_0} - \frac{1}{2R} \right) \approx 0$

例. 平行板电容器板间充满ε的介质, 间距S之间距d, 则在极板上带+Q和-Q的电荷, 外界需要抵抗静电力做多少功?

$$P_S = Q S, \quad D = \sigma = \frac{Q}{S}$$

$E = \frac{D}{\epsilon_0} = \frac{Q}{\epsilon_0 S}$

$W = \frac{1}{2} \epsilon_0 E^2 S d = \frac{1}{2} \frac{Q^2}{\epsilon_0 S^2} S d = \frac{Q^2 d}{2\epsilon_0 S}$

$V = Ed = \frac{Q}{C}, \quad C = \frac{S}{d}$

极板带电 Q . 对 $(0 \leq k \leq 1)$.空间若上电势 $k\varphi$, 电势差 $kV = k(\varphi_1 - \varphi_2)$.将电荷 Q 移动,

$$\text{外力做功 } SA = Q dk \times kV = QdkkV = QdV.$$

$$A = Q \int_0^1 k dk k V = \frac{1}{2} QV = \frac{1}{2} Q_1 \varphi_1 + \frac{1}{2} Q_2 \varphi_2$$

$= \frac{1}{2} (Q_1 + Q_2) V = (\frac{1}{2} DE) S d = (\frac{1}{2} D \cdot \frac{1}{\epsilon_0} V) S d.$

例. 环形电容器.

$$W = \frac{1}{2} (Q_1 \varphi_1 + \frac{1}{2} Q_2 \varphi_2) \\ = \frac{1}{2} (Q_1 \times \frac{1}{4\pi\epsilon_0} (\frac{1}{a} - \frac{1}{b})) + \frac{1}{2} \frac{(Q_1 + Q_2)}{4\pi\epsilon_0 d} \varphi_2$$

电荷量为Q, 部分的势能. $(Q_1 + Q_2)$ 部分.

$$W = \frac{1}{2} Q_1 \varphi_1 + \frac{1}{2} Q_2 \varphi_2 \\ = \frac{1}{2} Q_1 (\varphi_1 - \varphi_2) + \frac{1}{2} Q_2 (\varphi_1 + \varphi_2) \\ = \frac{1}{2} \frac{Q_1 + Q_2}{4\pi\epsilon_0 d} (\frac{1}{a} - \frac{1}{b}), \quad \varphi_2 = \frac{Q_1 + Q_2}{4\pi\epsilon_0 d}$$

$$\vec{E} = \begin{cases} \frac{Q_1}{4\pi\epsilon_0 r^2} \hat{r}, & a < r < b \\ 0, & b < r < d \\ \frac{Q_1 + Q_2}{4\pi\epsilon_0 r^2} \hat{r}, & r > d \end{cases}$$

$\varphi = \begin{cases} \frac{Q_1}{4\pi\epsilon_0 r^2} + \frac{Q_2}{4\pi\epsilon_0 d^2}, & a < r < b \\ \frac{Q_1 + Q_2}{4\pi\epsilon_0 r^2}, & b < r < d \\ \frac{Q_2}{4\pi\epsilon_0 r^2}, & r > d \end{cases}$

例. 平行板电容器.

$$\vec{E} = \frac{Q}{d\epsilon_0 S} \hat{d}, \quad \varphi = \frac{Q}{d\epsilon_0 S}$$

$W = \frac{1}{2} Q \varphi_1 + \frac{1}{2} (-Q) \varphi_2 = \frac{1}{2} QV$

$= \frac{1}{2} \epsilon_0 ES \times Ed = \frac{1}{2} \epsilon_0 E^2 S d.$